

[Order](http://www.ti.com/product/DRV8308?dcmp=dsproject&hqs=sandbuy&#samplebuy)  $\cdot$  Now





SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017

## **DRV8308 Brushless DC Motor Controller**

**Technical [Documents](http://www.ti.com/product/DRV8308?dcmp=dsproject&hqs=td&#doctype2)** 

### <span id="page-0-1"></span>**1 Features**

- <sup>1</sup> Three-Phase Brushless DC Motor Controller
	- Digital Closed-Loop Speed Control with Programmable Gain and Filters
- Drives 6 N-Channel MOSFETs With Configurable 10- to 130-mA Gate Drive
- Integrated Commutation from Hall Sensors
	- Timing Can Be Advanced/Delayed
	- 120° or 180°-Sinusoidal Current Control
	- Single Input Controls Motor Speed
- Operating Supply Voltage 8.5 to 32 V
- **Flexible Configuration Methods** 
	- Read Internal Non-Volatile Memory
	- Read External EEPROM
		- Write SPI
- Configurable Motor Current Limiter
- 5-V Regulator for Hall Sensors
- Low-power Standby Mode
- Integrated Overcurrent, Overvoltage, and Overtemperature Protection

### <span id="page-0-2"></span>**2 Applications**

- Industrial Pumps, Fans, and Valves
- <span id="page-0-3"></span>**White Goods**
- Power Tools and Lawn Equipment
- <span id="page-0-0"></span>**Printers**

### **3 Description**

Tools & **[Software](http://www.ti.com/product/DRV8308?dcmp=dsproject&hqs=sw&#desKit)** 

The DRV8308 controls sensored brushless DC motors with advanced features and a simple input interface. As a predriver, it drives the gates of 6 external N-Channel MOSFETs with a configurable current of 10mA to 130mA for optimal switching characteristics.

Support & **[Community](http://www.ti.com/product/DRV8308?dcmp=dsproject&hqs=support&#community)** 

 $22$ 

The 3 motor phases are commutated according to the Hall sensor inputs. Once the motor reaches a consistent speed, the DRV8308 uses just 1 Hall sensor to minimize jitter caused by sensor mismatch. The Hall signal-to-drive timing can be advanced or delayed in 0.1% increments to optimize power efficiency. An optional 180° commutation mode drives sinusoidal current through the motor and minimizes audible noise and torque ripple. Peak motor current can be controlled by sizing a sense resistor.

The DRV8308 achieves closed-loop speed control to spin motors to a precise RPM across a wide range of load torques. The system matches motor speed—generated from an FG trace or the Hall sensors—to the reference frequency on pin CLKIN. The DRV8308 can also drive motors open-loop using a duty cycle command, from either a clock or register setting.

An assortment of protection features bolster system robustness, as the DRV8308 handles and reports overcurrent, overvoltage, undervoltage, and overtemperature.

#### **Device Information[\(1\)](#page-0-0)**



(1) For all available packages, see the orderable addendum at the end of the datasheet.



#### **Simplified Schematic**

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, **44** intellectual property matters and other important disclaimers. PRODUCTION DATA.







### <span id="page-1-0"></span>**4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.



#### Changes from Original (February 2014) to Revision A **Page**







## <span id="page-2-0"></span>**5 Pin Configurations and Functions**



#### **Pin Functions**



(1)  $I = input$ , O = output, OD = open-drain output,  $I/O = input/output$ 

**[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)** SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

**NSTRUMENTS** 

Texas

#### **Pin Functions (continued)**

<span id="page-3-0"></span>

(2) In SPI mode, these pins are inputs; in EEPROM mode, they are open-drain outputs.

(3) When using FG amplifier, this pin is an analog input. If in TACH mode, this is a logic-level input.

![](_page_4_Picture_0.jpeg)

### **Pin Functions (continued)**

![](_page_4_Picture_68.jpeg)

### <span id="page-5-0"></span>**6 Specifications**

#### <span id="page-5-1"></span>**6.1 Absolute Maximum Ratings**

over operating free-air temperature (unless otherwise noted)<sup>(1)(2)(3)</sup>

![](_page_5_Picture_280.jpeg)

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values are with respect to network ground pin.

(3) Power dissipation and thermal limits must be observed

### <span id="page-5-2"></span>**6.2 Handling Ratings**

<span id="page-5-4"></span>![](_page_5_Picture_281.jpeg)

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### <span id="page-5-3"></span>**6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

![](_page_5_Picture_282.jpeg)

(1) Note that at VM  $<$  12 V, gate drive output voltage tracks VM voltage (2) Power dissipation and thermal limits must be observed

Power dissipation and thermal limits must be observed

(3)  $f_{HALL}$  of 50 Hz to 6.7 kHz is best (4) Operational with frequencies abo

Operational with frequencies above 50 kHz, but resolution is degraded

![](_page_6_Picture_0.jpeg)

#### <span id="page-6-0"></span>**6.4 Thermal Information**

<span id="page-6-1"></span>![](_page_6_Picture_97.jpeg)

(1) For more information about traditional and new thermal metrics, see the *[Semiconductor and IC Package Thermal Metrics](http://www.ti.com/lit/pdf/SPRA953)* application [report.](http://www.ti.com/lit/pdf/SPRA953)

Copyright © 2014–2017, Texas Instruments Incorporated *[Submit Documentation Feedback](http://www.go-dsp.com/forms/techdoc/doc_feedback.htm?litnum=SLVSCF7B&partnum=DRV8308)*

SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

#### <span id="page-7-0"></span>**6.5 Electrical Characteristics**

over operating free-air temperature range (unless otherwise noted)

![](_page_7_Picture_344.jpeg)

![](_page_8_Picture_0.jpeg)

### **Electrical Characteristics (continued)**

over operating free-air temperature range (unless otherwise noted)

<span id="page-8-1"></span><span id="page-8-0"></span>![](_page_8_Picture_272.jpeg)

SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

#### <span id="page-9-0"></span>**6.6 SPI Timing Requirements**

 $T_A = 25^{\circ}$ C, over recommended operating conditions unless otherwise noted  $(1)$ 

![](_page_9_Picture_193.jpeg)

(1) SMODE = Low<br>(2) These numbers

These numbers refer to the corresponding number in [Figure 1](#page-9-1)

![](_page_9_Figure_9.jpeg)

<span id="page-9-1"></span>**Figure 1. SPI Timing Requirements**

![](_page_10_Picture_0.jpeg)

### **6.7 Typical Characteristics**

<span id="page-10-0"></span>![](_page_10_Figure_4.jpeg)

![](_page_11_Picture_1.jpeg)

### <span id="page-11-0"></span>**7 Detailed Description**

#### <span id="page-11-1"></span>**7.1 Overview**

The DRV8308 device controls 3-phase brushless DC motors using a speed and direction input interface and Hall signals from the motor. The device drives N-channel MOSFETs with 10-V  $V_{GS}$ , and a configurable gate drive current of 10 to 130 mA.

There are three modes of speed input: clock frequency, clock duty cycle (pulse-width modulation), and an internal register that specifies duty cycle. In the Clock Frequency Mode, the device's digital speed control system matches motor speed with the input clock's frequency. Motor speed is either determined from the Halls sensors or signal on the FG input, which can be generated from a board trace underneath the motor that senses magnetic reluctance. The speed control system offers digital tuning of pole and zero frequencies and integrator gain. When properly tuned, the DRV8308 can drive motors with < 0.1% cycle jitter and fast torque compensation for varying loads. The duty cycle speed modes operate in open-loop without speed control.

When the DRV8308 device powers up, the configuration registers are set from either the one-time programmable (OTP) non-volatile memory, or from an external EEPROM (depending on the SMODE pin). After power-up, registers can be set in realtime over SPI, and the OTP memory can be permanently written once.

When the DRV8308 device begins spinning a motor, it initially uses all three Hall sensor phases to commutate. After a constant speed is reached, the LOCKn pin is pulled low and only one Hall sensor becomes used; this feature reduces jitter by eliminating the error caused by non-ideal Hall device placement and matching. Also at this time, commutation transitions to sine wave current drive (if enabled), which minimizes acoustic noise and torque ripple. Commutation timing can be tuned using the ADVANCE register for optimal performance and power efficiency.

<span id="page-11-2"></span>Numerous protection circuits prevent system components from being damaged during adverse conditions. Monitored aspects include motor voltage and current, gate drive voltage and current, and device temperature . When a fault occurs, the DRV8308 device stops driving and pulls FAULTn low, in order to prevent FET damage and motor overheating.

The DRV8308 device is packaged in a compact  $6 \times 6$ -mm, 40-pin QFN with a 0.5-mm pin pitch, and operates through an industrial ambient temperature range of –40°C to 85°C.

![](_page_12_Picture_0.jpeg)

#### **7.2 Functional Block Diagram**

<span id="page-12-0"></span>![](_page_12_Figure_4.jpeg)

**[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)** SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

#### <span id="page-13-0"></span>**7.3 Feature Description**

#### **7.3.1 Hall Comparators**

Three comparators are provided to process the raw signals from Hall effect transducers to commutate the motor. The Hall amplifiers sense zero crossings of the differential inputs and pass the information to digital logic.

The Hall amplifiers have hysteresis, and their detect threshold is centered at 0. Note, hysteresis is defined as shown in [Figure 4:](#page-13-1)

![](_page_13_Figure_7.jpeg)

**Figure 4. Hall Amplifier Hysteresis**

<span id="page-13-1"></span>In addition to the hysteresis, the Hall inputs are deglitched with a circuit that ignores any extra Hall transitions for a period of 20 μs after sensing a valid transition. This prevents PWM noise from being coupled into the Hall inputs, which can result in erroneous commutation.

If excessive noise is still coupled into the Hall comparator inputs, it may be necessary to add capacitors between the + and – inputs of the Hall comparators, and (or) between the input or inputs and ground.

The ESD protection circuitry on the Hall inputs implements a diode to VREG. Because of this diode, the voltage on the Hall inputs should not exceed the VREG voltage.

Since VREG is disabled in standby mode (ENABLE inactive), the Hall inputs should not be driven by external voltages in standby mode. If the Hall sensors are powered from VREG or from VSW, this is specified by the DRV8308 device; however, if the Hall sensors are powered externally, they should be disabled if the DRV8308 is put into standby mode. In addition, they should be powered-up before enabling the motor, or an invalid Hall state may cause a delay in motor operation.

#### **7.3.2 FG Amplifier, Comparator, and FG Output**

An FG amplifier and comparator provide rotational feedback from an external magnetic reluctance sensor. A diagram of the FG circuit is shown in [Figure 5](#page-14-0):

![](_page_14_Picture_0.jpeg)

#### **Feature Description (continued)**

![](_page_14_Figure_4.jpeg)

**Figure 5. FG Circuit Diagram**

<span id="page-14-0"></span>The output of the FG amplifier is provided on a pin, so the gain of the FG amplifier can be set by the user. Filter circuits can also be implemented.

Note that the FG signal is also fed back internally to the speed control circuits.

The FG signal that the DRV8308 device uses can be generated from a PCB trace under a motor, or it can be input from a logic-level TACH input, or it can be synthesized from the Hall sensor transitions (selectable by register FGSEL). If generated from Hall transitions, the resulting output can be either an exclusive-or function of the three Hall sensors, or the same as the HALL\_U input, as shown in [Figure 6.](#page-15-0)

Selection of FG operating mode is through the FGSEL register bits.

The FGOUT pin is an open-drain output and requires an external pullup resistor to the logic supply.

#### **Feature Description (continued)**

![](_page_15_Figure_4.jpeg)

#### <span id="page-15-0"></span>**7.3.3 Enable, Reset, and Clock Generation**

The ENABLE pin is used to start and stop motor operation. ENABLE can be programmed to be active high or active low, depending on the state of the ENPOL bit; if ENPOL = 0, ENABLE is active high. If ENPOL = 1, the ENABLE pin is active low.

The polarity of ENABLE cannot be modified during operation through register writes; it is controlled only by the contents of the ENPOL bit in OTP memory.

When ENABLE is active, operation of the motor is enabled. When ENABLE is made inactive, the speed control loop is reset, and the motor either brakes or coasts depending on the state of the BRKMOD bit. After motor rotation has stopped (when no transitions occur on the FGOUT pin for a period of 1 s), the DRV8308 device enters a low-power standby state. In the standby state, the motor driver circuitry is disabled (all gate drive outputs are driven low, so the FET outputs are high-impedance), the gate drive regulator and charge pump are disabled, the VREG regulator and VSW power switch are disabled, and all analog circuitry is placed into a low power state. The digital circuitry in the device still operates in standby mode.

All internal logic is reset in three different ways:

- 1. Upon device power-up.
- 2. When VM drops below  $V_{\text{RESET}}$ .
- 3. When the RESET pin is high while ENABLE is active.

If RESET is high while ENABLE is inactive, then the registers read as 1. If the RESET pin is not needed, it can be connected to GND. The RESET input is deglitched with a 10-µs timer on assertion and deassertion.

An internal clock generator provides all timing for the DRV8308 device. The master oscillator runs at 100 MHz. This clock is divided to a nominal 50-MHz frequency that clocks the remainder of the digital logic.

![](_page_16_Picture_0.jpeg)

#### **Feature Description (continued)**

#### **7.3.4 Commutation**

For 3-phase brushless DC motors, rotor position feedback is provided from Hall effect transducers mounted on the motor. These transducers provide three overlapping signals, each 60° apart. The windings are energized in accordance with the signals from the Hall sensors to cause the motor to move.

In addition to the Hall sensor inputs, commutation is affected by a direction control, which alters the direction of motion by reversing the commutation sequence. Control of commutation direction is by the DIRPOL register bit as well as the DIR input pin. The DIRPOL register bit is combined with the pin with an exclusive-OR function as follows:

<b>DIR PIN</b>	<b>DIRPOL REGISTER BIT</b>	<b>RESULTING DIR FOR</b> <b>COMMUTATION</b>

**Table 1. Direction Behavior**

<span id="page-16-0"></span>If the commanded direction is changed while the motor is still spinning, this may cause excessive current flow in the output stage.

The DRV8308 device supports three commutation modes: standard 120° commutation using three Hall sensors, 120° commutation using a single Hall sensor, and 180° sine-wave-drive commutation.

In standard 120° commutation, mis-positioning of the Hall sensors can cause motor noise, vibration, and torque ripple. 120° commutation using a single Hall sensor (single-Hall commutation) can improve motor torque ripple and vibration because it relies on only one Hall edge for timing.

180° sine-wave-drive commutation is even more advanced, and excites the windings with a waveform that delivers nearly sinusoidal current to each winding.

#### *7.3.4.1 120° 3-Hall Commutation*

In standard 120° commutation, the motor phases are energized using simple combination logic based on all three Hall sensor inputs. Standard 120° commutation is in accordance with [Table 2](#page-16-1), [Figure 7,](#page-17-0) and [Figure 8:](#page-18-0)

<span id="page-16-1"></span>![](_page_16_Picture_204.jpeg)

![](_page_16_Picture_205.jpeg)

<sup>(1)</sup> Hall sensor is "H" if the positive input pin voltage is higher than the negative input pin voltage. States 1X and 2X are illegal input combinations.

<sup>(2)</sup> During states where the phase is driven with a PWM signal, using asynchronous rectification, the LS gate is held off (L); using synchronous rectification, the LS gate is driven with the inverse of the HS gate.

**[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)**

![](_page_17_Picture_1.jpeg)

SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

![](_page_17_Figure_3.jpeg)

Standard 120° Commutation (DIR = 1)

<span id="page-17-0"></span>**Figure 7. Standard 120° Commutation (DIR = 1)**

![](_page_18_Picture_0.jpeg)

![](_page_18_Figure_3.jpeg)

**Figure 8. Standard 120° Commutation (DIR = 0)**

#### <span id="page-18-0"></span>*7.3.4.2 120° Single-Hall Commutation*

To generate commutation timing for single-Hall commutation, a digital timer is used to create a clock that runs at 960<sup>x</sup> the Hall sensor frequency. Only one Hall sensor input, HALL\_U, is used for commutation; this eliminates any torque ripple caused by mechanical or electrical offsets of individual Hall sensors.

Single-Hall commutation is only enabled when the register BASIC  $= 0$  and the motor is operating at a nearly constant speed or speed-locked condition. To control this function, logic is used to determine when the speed is constant and the speed control loop is locked. This logic generates the LOCK signal. The LOCK signal is also output on the LOCKn pin.

Except in PWM input modes, LOCK is also prevented from being signaled if the speed control loop integrator is saturated (either at 0 or full-scale), which indicates that the speed control loop is not locked.

Until LOCK goes active (for example, at start-up, stop, or application of a sudden load that causes motor speed to drop very quickly), standard 120° commutation is used. Because of this, three Hall sensors are required regardless of which commutation method is used.

The commutation timer drives a counter that can be offset with a value programmed in the ADVANCE register. This value allows the phase of commutation to be shifted relative to the actual Hall sensor transitions. Note that the phase advance is not functional in standard 120° commutation. The phase advance also has an automatic mode where the advance value is scaled according to motor speed (see *[Auto Gain and Advance Compensation](#page-32-0)*).

Copyright © 2014–2017, Texas Instruments Incorporated *[Submit Documentation Feedback](http://www.go-dsp.com/forms/techdoc/doc_feedback.htm?litnum=SLVSCF7B&partnum=DRV8308)*

![](_page_19_Picture_1.jpeg)

Timing of 120° single-Hall commutation is essentially the same as standard 120° commutation shown previously. However, there are small time differences of when the transitions occur.

#### *7.3.4.3 180° Sine-Wave-Drive Commutation*

180° sine-wave-drive commutation uses a single Hall sensor to generate commutation timing, as described for 120° single-Hall commutation. In addition, the value of the commutation timer modulates the duty cycle of the outputs in accordance with a fixed pattern that approximates sinusoidal current through the windings.

The output of the commutation block is a 12-bit modulation value for each motor phase (U, V, and W) that represents the duty cycle modulation of the PWM for each output. Note that during 120° commutation, these values are either 0 or set to a constant value derived from the MOD120 register.

When using sine mode, MOD120 should be set to 3970.

![](_page_19_Figure_8.jpeg)

**Figure 9. 180° Sine-Wave-Drive Commutation**

During 180° sine-wave-drive commutation, commutation transitions occur midway between Hall transitions. The PWM duty cycle is modulated to provide sinusoidal current waveforms. Commutation (shown for asynchronous rectification) is in accordance with the table and diagrams below. Note that the diagrams show a representation of duty cycle, not level, for the PWM states.

	<b>HALL INPUTS</b>						<b>PRE-DRIVE OUTPUTS</b>					
<b>STATE</b>	$DIR = 1$			$DIR = 0$		<b>PHASE U</b>		<b>PHASE V</b>		<b>PHASE W</b>		
	$U_H$	VH	W H	U_H	$V_H$	W_H	<b>U HSGATE</b>	<b>U LSGATE</b>	<b>V HSGATE</b>	<b>V LSGATE</b>	<b>W HSGATE</b>	<b>W LSGATE</b>
			н	н	H		<b>PWM</b>	L / $!$ PWM $^{(2)}$	<b>PWM</b>	L / !PWM <sup>(2)</sup>		H
$\overline{c}$		н	н	н			<b>PWM</b>	L / $!$ PWM $^{(2)}$	<b>PWM</b>	L / $!$ PWM $^{(2)}$		H
3		Н		н		Н	<b>PWM</b>	L / $!$ PWM $^{(2)}$		H	<b>PWM</b>	L / $!$ PWM $^{(2)}$
4	Н	Н				Н	<b>PWM</b>	$L / !$ PWM $^{(2)}$		н	<b>PWM</b>	L / !PWM <sup>(2)</sup>
5	Н				н	H		H	<b>PWM</b>	L / !PWM <sup>(2)</sup>	<b>PWM</b>	L / !PWM <sup>(2)</sup>
6	H		H		H			н	<b>PWM</b>	L / !PWM <sup>(2)</sup>		L / !PWM <sup>(2)</sup>
1X	H	H	H	<b>.</b>		┕				ш.		
2X				н	H	H						

**Table 3. Commutation for Asynchronous Rectification(1)**

- (1) Hall sensor is "H" if the positive input pin voltage is higher than the negative input pin voltage. States 1X and 2X are illegal input combinations.
- (2) During states where the phase is driven with a PWM signal, using asynchronous rectification, the LS gate is held off (L); using synchronous rectification, the LS gate is driven with the inverse of the HS gate.

![](_page_20_Picture_0.jpeg)

180° Sine Commutation (DIR = 1)

![](_page_20_Figure_4.jpeg)

![](_page_21_Picture_1.jpeg)

![](_page_21_Figure_3.jpeg)

180° Sine Commutation (DIR = 0)

**Figure 11. 180° Sine Commutation (DIR = 0)**

![](_page_22_Picture_0.jpeg)

#### **7.3.5 Commutation Logic Block Diagram**

A block diagram of the commutation logic is shown in [Figure 12](#page-22-0).

![](_page_22_Figure_5.jpeg)

**Figure 12. Commutation Logic**

#### <span id="page-22-0"></span>**7.3.6 Commutation Parameters**

A number of commutation parameters are programmable through registers accessed through the serial interface, including:

- ADVANCE The phase of commutation is advanced (or delayed) relative to the Hall sensor transition by this 8-bit amount. Units are in commutation clocks, which is 1 / 960 of the HALL\_U period. Note that phase advance is only applicable in single-Hall commutation modes. An automatic phase advance compensation mode can also be enabled by the AUTOADV bit (see *[Auto Gain and Advance Compensation](#page-32-0)* for details).
- DELAY if set, commutation is delayed relative to Hall transitions; if cleared, commutation is advanced relative to Hall transitions.
- BASIC If set, commutation is a basic 120° 3-Hall mode with no ADVANCE.
- ENSINE The ENSINE bit, when set, selects 180° sinusoidal commutation. The BASIC bit must also be 0.
- HALLRST HALLRST sets how many HALL\_U cycles pass for each commutation counter reset. In other words, the commutation counter is reset every N HALL\_U edges. Selections available are 1, 2, 4, and 8.
- MINSPD Sets the minimum Hall U period that LOCK can be set. The 8-bit field represents 2.56 ms/count, with a max value of 652.8 ms.
- SPDREVS After the MINSPD and SPEEDTH criteria are met, SPDREVS adds a minimum number of Hall U periods that must occur for LOCK to be set.
- SPEEDTH Sets how much speed variation is allowed across Hall\_U periods while keeping LOCK set. This 3-bit field sets the percentage variation allowed by changing a programmable divider. Divisions of 1/4, 1/8, 1/16, 1/32, 1/64, 1/128, 1/256, and 1/512 are supported. These divisors correspond to 25%, 12.5%, 6.25%,

3.13%, 1.56%, 0.78%, 0.39%, and 0.20% variation per revolution.

• SPEED — In the Internal Register PWM Mode, SPEED divided by 4095 sets the input duty cycle. In Clock Frequency Mode, SPEED sets the open-loop gain during spin-up before LOCKn goes Low.

The diagram below shows how the lock parameters (MINSPD, SPEEDTH, and SPDREV) affect commutation mode.

![](_page_23_Figure_6.jpeg)

**Figure 13. Commutation Parameters**

#### **7.3.7 Braking**

Motor braking can be initiated by the BRKPOL register bit as well as the BRAKE pin. The BRKPOL register bit can also be used to program the polarity of the BRAKE pin, as it is combined with the pin with an exclusive-OR function as follows:

![](_page_23_Picture_186.jpeg)

#### **Table 4. Brake Behavior**

When the motor is braking, all low-side drivers are held in an on state, causing all low-side FETs to turn on, and the integrator is reset to 0.

In addition, braking can be entered when the ENABLE pin is made inactive. BRKMOD controls the behavior of the outputs when ENABLE is inactive. If BRKMOD= 0, the outputs are 3-stated, resulting in the motor coasting; if BRKMOD = 1, all low-side FETs are turned on, causing the motor to brake.

**BRKMOD = 0 COAST BRKMOD = 1 BRAKE**  $RESET = 1$  <br> Coast  $|$  Brake  $BRAKE = active$  Brake Brake Brake  $ENABLE = inactive$  Coast Brake DIR | Coast | Brake Clock off  $\qquad$  Brake  $\qquad$  Brake Power down | Coast | Brake

#### **Table 5. BRKMOD**

#### **7.3.8 Output Pre-Drivers**

The output drivers for each phase consist of N-channel and P-channel MOSFET devices arranged as a CMOS buffer. They are designed to directly drive the gate of external N-channel power MOSFETs.

The outputs can provide synchronous or asynchronous rectification. In asynchronous rectification, only the highside FET is turned on and off with the PWM signal; current is recirculated using external diodes, or the body diodes of the external FETs. In synchronous rectification, the low side FET is turned on when the high side is turned off.

Synchronous rectification is enabled or disabled using the SYNRECT control bit. When set to 1, synchronous rectification is used. In general, synchronous rectification results in better speed control and higher efficiency.

The high-side gate drive output UHSG is driven to VCP whenever the duty cycle output U\_PD from the PWM generator is high, the enable signal U\_HS from the commutation logic is active, and the current limit (V<sub>LIMITER</sub>) is not active. If the high-side FET is on and a current limit event occurs, the high-side FET is immediately turned off until the next PWM cycle.

The low-side gate drive ULSG is driven to VM whenever the internal signal U\_LS is high, or whenever synchronous rectification is active and UHSG is low.

Phases V and W operate in an identical fashion.

![](_page_24_Figure_11.jpeg)

**Figure 14. Predriver Circuit**

![](_page_25_Figure_3.jpeg)

**Figure 15. Drive Timing**

The peak drive current of the pre-drivers is adjustable by setting the IDRIVE register bits. Peak drive currents may be set between 10 and 130 mA. Adjusting the peak current changes the output slew rate, which also depends on the FET input capacitance and gate charge.

When changing the state of the output, the peak current is applied for a short period of time  $(t_{DRIVE})$ , to charge the gate capacitance. This time is selected by setting the TDRIVE register bits. Times of 1, 5, 10, or 15 µs may be selected. After this time, a weak current source is used to keep the gate at the desired state. When selecting the gate drive strength for a given external FET, the selected current must be high enough to fully charge and discharge the gate during the time when driven at full current, or excessive power is dissipated in the FET.

During high-side turn-on, the low-side gate is held low with a low impedance. This prevents the gate-source capacitance of the low-side FET from inducing turn-on. Similarly, during low-side turn-on, the high-side gate is held off with a low impedance.

The pre-driver circuits include enforcement of a dead time in analog circuitry, which prevents the high-side and low-side FETs from conducting at the same time. Additional dead time can be added (in digital logic) by setting the DTIME register bits.

#### **7.3.9 Current Limit**

The current limit circuit activates if the voltage detected across the low-side sense resistor exceeds  $V_{LIMITEB}$ . This feature restricts motor current to less than V<sub>LIMITER</sub>/R<sub>ISENSE</sub>, and it reduces the requirements of the external power supply. Note that the current limit circuit is ignored immediately after the PWM signal goes active for a short blanking time, to prevent false trips of the current limit circuit.

If current limit activates, the high-side FET is disabled until the beginning of the next PWM cycle. If synchronous rectification is enabled when the current limit activates, the low-side FET is activated while the high-side FET is disabled.

#### **7.3.10 Charge Pump**

Since the output stages use N-channel FETs, a gate drive voltage higher than the VM power supply is needed to fully enhance the high-side FETS. The DRV8308 device integrates a charge pump circuit that generates a voltage approximately 10 V more than the VM supply for this purpose.

The charge pump requires two external capacitors for operation. For details on these capacitors (value, connection, and so forth), refer to the *Pin Functions* table in the *[Pin Configurations and Functions](#page-2-0)* section.

The charge pump is shutdown when in standby mode (ENABLE inactive).

![](_page_26_Figure_7.jpeg)

**Figure 16. Charge Pump**

#### **7.3.11 5-V Linear Regulator**

A 5-V linear regulator (VREG) is provided to power internal logic and external circuitry, such as the Hall effect sensors.

A capacitor must be connected from the VREG output to ground, even if the output is not used for external circuitry. The recommended capacitor value is a 0.1-μF, 10-V ceramic capacitor.

The VREG output is designed to provide up to 30-mA output current, but power dissipation and thermal conditions must be considered. As an example, with 24 V in and 20 mA out, power dissipated in the linear regulator is 19 V  $\times$  20 mA = 380 mW.

The VREG regulator is shutdown in standby mode (when ENABLE is inactive).

#### **7.3.12 Power Switch**

A low-current switch is provided in the DRV8308 device that can be used to power the Hall sensors or other external circuitry through the VSW pin. When ENABLE is active the switch is turned on, connecting the VSW pin to VM. When ENABLE is inactive the switch is turned off (standby mode).

#### **7.3.13 Protection Circuits**

A number of protection circuits are included in the DRV8308 device. Faults are reported by asserting the FAULTn pin (an active-low, open-drain output signal), as well as setting the appropriate bit or bits in the FAULT register. Note that bits in the FAULT register remain set until either a 0 is written to them, RESET is asserted, or the device power is cycled.

#### *7.3.13.1 VM Undervoltage Lockout (UVLO)*

If the VM power supply drops, there may not be enough voltage to fully turn on the output FETs. Operation in this condition causes excessive heating in the output FETs. To protect against this, the DRV8308 device contains an undervoltage lockout circuit.

Copyright © 2014–2017, Texas Instruments Incorporated *[Submit Documentation Feedback](http://www.go-dsp.com/forms/techdoc/doc_feedback.htm?litnum=SLVSCF7B&partnum=DRV8308)*

In the event that the VM supply voltage drops below the undervoltage lockout threshold  $(V_{UVLO})$ , the FAULTn pin is driven active and the motor driver is disabled. After VM returns to a voltage above the undervoltage lockout threshold, the FAULTn pin is high impedance and operation of the motor driver automatically resumes.

The UVLO bit in the FAULT register is set. This bit remains set until a 0 is written to the UVLO bit.

At power-up, the UVLO bit is set.

Note that register reads and writes are still possible during the UVLO condition, as long as VM stays above the VM reset threshold. If VM drops below the VM reset threshold, all registers are reset and register read or write is not functional.

#### *7.3.13.2 VM Overvoltage (VMOV)*

In some cases, if synchronous rectification is used, energy from the mechanical system can be forced back into the VM power supply. This can result in the VM power supply being boosted by the energy in the mechanical system, causing breakdown of the output FETs, or damaging the DRV8308 device. To protect against this, the DRV8308 device has overvoltage protection.

There are two overvoltage thresholds, selectable by the OVTH bit. An overvoltage event is recognized if the VM voltage exceeds the selected overvoltage threshold (VM<sub>OVLO</sub>). Note that for the output FETs to be protected, they must be rated for a voltage greater than the selected overvoltage threshold.

In the event of an overvoltage, the FAULTn pin is pulled low. If synchronous rectification is enabled, the output stage is forced into asynchronous rectification. After VM returns to a voltage below the overvoltage threshold, the FAULTn pin is high impedance. If synchronous rectification was enabled prior to the overvoltage event, after a fixed 60-µs delay, synchronous rectification is re-enabled.

The VMOV bit in the FAULT register is set. This bit remains set until a 0 is written to the VMOV bit.

#### *7.3.13.3 Motor Overcurrent (OCP)*

Overcurrent protection (OCP) is provided on each FET in addition to the current limit circuit. The OCP circuit is designed to protect the output FETs from atypical conditions such as a short circuit between the motor outputs and each other, power, or ground.

The OCP circuit is independent from the current limit circuitry. OCP works by monitoring the voltage drop across the external FETs when they are enabled. If the voltage across a driven FET exceeds  $V_{FETOCP}$  for more than  $t_{OCP}$ an OCP event is recognized. V $F_{F\text{FIOCP}}$  is configurable by register OCPTH and  $t_{OCP}$  is configurable by register OCPDEG.

In addition to monitoring the voltage across the FETs, an OCP event is triggered if the voltage applied to the ISEN pin exceeds the  $V_{\text{SENSEOCP}}$  threshold voltage.

In the event of an OCP event, FAULTn is pulled low, and the motor driver is disabled.

After a fixed delay of 5 ms, the FAULTn pin is driven inactive and the motor driver is re-enabled.

The OCP bit in the FAULT register is set when an OCP event is recognized. This bit remains set until a 0 is written to the OCP bit.

#### *7.3.13.4 Charge Pump Failure (CPFAIL)*

If the voltage generated by the high-side charge pump is too low, the high-side output FETs are not fully turned on, and excessive heating results. To protect against this, the DRV8308 device has a circuit that monitors the charge pump voltage.

If the charge pump voltage drops below VCPFAIL, the FAULTn pin is pulled low and the motor driver is disabled. After the charge pump voltage returns to a voltage above the VCPFAIL threshold, the FAULTn pin is high impedance and operation of the motor driver automatically resumes.

The CPFAIL bit in the FAULT register is set when the charge pump voltage drops below VCPFAIL. This bit remains set until a 0 is written to the CPFAIL bit.

At power-up, the CPFAIL bit is set.

![](_page_28_Picture_0.jpeg)

### **[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308) [www.ti.com](http://www.ti.com)** SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017

#### *7.3.13.5 Charge Pump Short (CPSC)*

To protect against excessive power dissipation inside the DRV8308 device, a circuit monitors the charge pump and disables it in the event of a short circuit on the PCB.

If a short circuit is detected on the charge pump, the FAULTn pin is pulled low and the motor driver is disabled. After a fixed period of 5 s, the FAULTn pin is high impedance and operation of the motor driver automatically resumes. If the short circuit condition is still present, the cycle repeats.

<span id="page-28-0"></span>The CPSC bit in the FAULT register is set when a short circuit is detected on the charge pump. This bit remains set until a 0 is written to the CPSC bit.

#### *7.3.13.6 Overtemperature (OTS)*

To protect against any number of faults that could result in excessive power dissipation inside the device, the DRV8308 device includes overtemperature protection.

Overtemperature protection activates if the temperature of the die exceeds the OTS threshold temperature  $(T_{TSD})$ . If this occurs, the FAULTn pin is pulled low, the device is disabled and the OTS bit in the FAULT register is set. This OTS bit remains set until a 0 is written to the OTS bit.

If the RETRY bit is set after the temperature has fallen below the OTS threshold, the part re-enables itself after a fixed delay of 5 s.

If the RETRY bit is not set, the part disables the pre-drivers until RESET is asserted, or until power has been removed and re-applied to the device.

![](_page_29_Picture_1.jpeg)

#### <span id="page-29-0"></span>**7.4 Device Functional Modes**

#### **7.4.1 Modes of Speed Input**

The DRV8308 device is designed to support a wide range of motor speeds and constructions. Speeds of up to approximately 50000 RPM are supported with motor constructions of up to 16 poles, or corresponding lower speeds with more poles. This translates into a Hall sensor speed of up to 6.7 kHz. (The frequency of one Hall sensor can be calculated by RPM  $\times$  (motor poles) / 120.)

Speed control of the motor is accomplished by varying the duty cycle applied to the external FETs. Three methods of speed control input are possible with the DRV8308 device:

- **Clock Frequency Mode**: This is closed-loop speed control that locks the FGOUT frequency with the CLKIN frequency.
- **Clock PWM Mode**: This is open-loop, where the duty cycle of the clock on CLKIN scales the speed of the motor.
- **Internal Register PWM Mode**: This is open-loop, where register SPEED divided by 4095 commands the input duty cycle.

The mode used is set by the SPDMODE register.

#### *7.4.1.1 Clock Frequency Mode*

For a practical guide on tuning closed-loop speed control, refer to Section 3 of the*[DRV8308EVM User's Guide](http://www.ti.com/lit/pdf/slvua41)*.

In Clock Frequency Mode, the clock signal is deglitched by the 51.2-MHz clock. The deglitched input, along with the FG signal (derived from the FG amplifier, TACH input, or the Hall sensors), are input to a speed differentiator, where the CLKIN signal is compared to the actual speed of the motor (determined by the FG frequency). The speed differentiator outputs are UP and DOWN pulses.

The deglitcher and speed differentiator are shown in [Figure 17:](#page-29-1)

![](_page_29_Figure_15.jpeg)

**Figure 17. Deglitcher and Speed Differentiator**

<span id="page-29-1"></span>The UP and DOWN outputs of the speed differentiator are integrated by accumulating the value set by the SPDGAIN register for each cycle of the integrator clock (CLK50 divided by the value of the INTCLK register) that an UP or DOWN signal is active. If UP is active, the amount is added to the current integrator output; if the DOWN input is active, the value is subtracted. If neither signal is active, the integrator output remains the same. Note that the integrator output is reset to 0 at any time the motor is disabled or in brake, and at reset. The integrator output does not roll over at maximum or minimum count.

At the moment that ENABLE is made active, the integrator and filters are reset to 0. If there are no transitions on the CLKIN pin, no UP pulses are generated, so the integrator remains at 0, and the motor is not driven.

Once the motor is running, if the signal on CLKIN stops, DOWN pulses are generated until the integrator reaches 0. This actively decelerates the motor (brake) until the motor stops.

![](_page_30_Picture_0.jpeg)

The output of the integrator is applied to a programmable digital filter. The filter has one pole and one zero. The pole location is programmable from approximately 100 to 1600 Hz, and is set via the FILK1 register; the zero location is programmable from 2 to 100 Hz and is set via the FILK2 register. The filter may be bypassed by setting the BYPFILT bit.

For a given pole and zero frequency, FILK1 and FILK2 are calculated as follows:

$$
\text{FILK2} = 2^{19} \frac{2\pi \frac{f_{z}}{f_{s}}}{1 + \pi \frac{f_{z}}{f_{s}}}, \qquad \text{FILK1} = 2^{16} \frac{2\pi \frac{f_{p}}{f_{s}}}{1 + \pi \frac{f_{p}}{f_{s}}}
$$

where

- $f<sub>z</sub>$  is the desired zero frequency
- $f<sub>p</sub>$  is the desired pole frequency
- $f_s$  is the filter sample rate (195000 Hz)
- The result is rounded to the nearest integer (1) (1)

Following the filter is a programmable lead compensator, which also contains one pole and one zero. The compensator characteristics are programmable by the COMPK1 and COMPK2 registers. Center frequency is programmable between 20 and 100 Hz, with a phase lead between 0° and 80°. The compensator may be bypassed by setting the BYPCOMP bit.

For a given pole and zero frequency, COMPK1 and COMPK2 are calculated as follows:

COMPK2 = 
$$
2^{19} \frac{2\pi \frac{f_z}{f_s}}{1 + \pi \frac{f_z}{f_s}}
$$
, COMPK1 =  $2^{16} \frac{2\pi \frac{f_p}{f_s}}{1 + \pi \frac{f_p}{f_s}}$ 

where

- $f<sub>z</sub>$  is the desired zero frequency
- $f<sub>p</sub>$  is the desired pole frequency
- $f_s$  is the filter sample rate (195000 Hz)
- The result is rounded to the nearest integer (2)

The filter and compensator ratios also scale DC gain in the same way as LOOPGAIN. DC gain is scaled by 2×(FILK2/FILK1) and 0.5×(COMPK2/COMPK1).

The digital filter and compensator are reset to 0 whenever the motor is disabled.

The integrator, filter, and lead compensator result in a typical open-loop response as shown in [Figure 18.](#page-31-0) Note that the locations of the poles and zeros are not restricted to what is shown.

![](_page_31_Picture_0.jpeg)

![](_page_31_Figure_4.jpeg)

**Figure 18. Open-Loop Response**

<span id="page-31-0"></span>The integrator operates on the periods of CLKIN and the Feedback as shown in [Figure 19](#page-31-1):

![](_page_31_Figure_7.jpeg)

**Figure 19. Integrator and Filters**

#### <span id="page-31-1"></span>*7.4.1.2 Clock PWM and Internal Register PWM Modes*

In PWM input modes, the PWM input signal is timed using a 50 MHz clock to generate a 12-bit number that corresponds to the duty cycle of the incoming PWM signal. The input PWM frequency should be between 16 and 50 kHz, higher PWM frequencies work, but resolution is degraded. Note that the gate driver's output PWM frequency is independent of the speed control PWM input frequency; the output PWM frequency is selected by the PWMF register bits.

The measured input duty cycle is scaled by the contents of the MOD120 register. With a full-scale MOD120 register (4095 decimal), the output duty cycle is  $2 \times$  the input duty cycle. To make the output duty cycle equal to the input, a value of 2048 decimal should be written to MOD120.

An additional multiplication factor of 2 is introduced when the BYPCOMP bit is set; if BYPCOMP is set, the output duty cycle is 4× the input duty cycle (when MOD120 is 4095).

![](_page_32_Picture_0.jpeg)

In register speed control mode, a 12-bit register SPEED is used to directly provide the speed command.

During sine commutation, the input duty cycle is multiplied by the modulation values for each phase (MOD\_U, MOD\_V, and MOD\_W) to generate a 12-bit value that determines the output PWM duty cycle of each phase. Note that in 120° commutation, the MOD values are fixed at a duty cycle that is set by the MOD120 register.

The PWM frequency can be set to either 25, 50, 100, or 200 kHz, with register PWMF. Lower PWM frequencies are desirable to minimize switching losses; higher PWM frequencies provide better control resolution, especially at very high motor speeds.

The outputs of the PWM generators are the signals U\_PD, V\_PD, and W\_PD. These contain the duty cycle information for each phase.

Modulation and PWM generation is shown in [Figure 20:](#page-32-1)

![](_page_32_Figure_8.jpeg)

**Figure 20. Modulation and PWM Generation**

#### <span id="page-32-1"></span><span id="page-32-0"></span>**7.4.2 Auto Gain and Advance Compensation**

The DRV8308 device provides modes to automatically scale the loop gain and the phase advance settings based on motor speed. This helps improve loop stability and motor performance in cases where the motor must operate over a wide speed range with a single set of parameters. For applications that run at only one speed, these functions should be left disabled.

Auto gain compensation is enabled by setting the AUTOGAIN bit. Auto gain will scale the LOOPGAIN of the system using the following equation:

$$
Compute d Gain = (LOOPGAIN / AG\_SETPT) \times f_{CLKIN}
$$
\n(3)

Automatic advance is enabled by setting the AUTOADV bit. The advance setting is scaled such that at zero speed, there is no phase advance. As speed increases, the phase advance is increased using the equation below:

Computed Advance = (ADVANCE / AA\_SETPT) × f<sub>Hall</sub> U (4)

Both the gain and advance values are latched when LOCK goes active (when the motor is at constant speed).

The auto gain and advance functions are shown in [Figure 21:](#page-33-0)

33

![](_page_33_Figure_4.jpeg)

**Figure 21. Auto Gain and Advance Functions**

#### <span id="page-33-2"></span><span id="page-33-0"></span>**7.4.3 External EEPROM Mode**

A serial EEPROM can be connected to the serial port to load the register contents. To activate external EEPROM mode, connect the SMODE pin to logic high. This causes the SPI interface to act as a master, and load data from an external EEPROM. The DRV8308 device latches data on the falling edge of SCLK.

The serial EEPROM should be a microwire-compatible, 16-bit-word device, such as the 93C46B. The VREG power supply can be used to power the EEPROM. Connections are as shown in [Figure 22](#page-33-1):

![](_page_33_Figure_9.jpeg)

#### **Figure 22. EEPROM Mode Connections**

<span id="page-33-1"></span>Data in the EEPROM should be arranged starting at address 0 exactly as shown in [Table 6](#page-35-1). EEPROM data bits 12 to 15 are unused.

![](_page_34_Picture_0.jpeg)

To program the EEPROM device in-circuit while connected to the DRV8308 device, place the DRV8308 device into the reset state by driving RESET high. This 3-states the serial interface pins and allows them to be overdriven by external programming logic. Alternatively, the EEPROM may be programmed off-board before assembly. The DRV8308 device cannot program an EEPROM.

#### <span id="page-34-0"></span>**7.5 Programming**

#### **7.5.1 Serial Interface**

A simple SPI serial interface is used to write to the control registers in the DRV8308 device. Optionally, the interface can be configured to automatically load the registers from an external EEPROM device.

Data is shifted into a holding register when SCS is active high. When SCS is returned to inactive (low), the data received is latched into the addressed register.

#### **7.5.2 Serial Data Format**

The serial data consists of a 24-bit serial write, with a read or write bit, 7 address bits, and 16 data bits. The address bits identify one of the registers defined in [Table 8](#page-37-0).

To write to a register, data is shifted in after the address as shown in [Figure 23:](#page-34-1)

![](_page_34_Figure_12.jpeg)

- A. Any amount of time may pass between bits, as long as SCS stays active high. This allows 8-bit writes to be used.
- B. Any additional clock edges encountered after the  $24<sup>th</sup>$  edge are ignored.

#### **Figure 23. SDF Timing Diagram 1**

<span id="page-34-1"></span>Data may be read from the registers through the SDATO pin. During a read operation, only the address is used from the SDATI pin; the data bits following are ignored. Reading is enabled by setting the READ bit at the beginning of the access:

SDATI | YREAD \{ A6 \{ A5 \{ A4 \{ A3 SDATO D15 D10 D9 D8 D7 D6 D5 D4 D3 D2 D1 D0 D14 D13 D12 D11 SCS SCLK  $\begin{pmatrix} 1 & 2 \\ 3 & 3 \end{pmatrix}$   $\begin{pmatrix} 4 \\ 4 \end{pmatrix}$   $\begin{pmatrix} 5 \\ 5 \end{pmatrix}$   $\begin{pmatrix} 6 \\ 5 \end{pmatrix}$   $\begin{pmatrix} 7 \\ 8 \end{pmatrix}$  Note 1  $\begin{pmatrix} 1 & 10 \\ 10 & 11 \end{pmatrix}$   $\begin{pmatrix} 1 & 12 \\ 12 & 13 \end{pmatrix}$   $\begin{pmatrix} 14 \\ 15 \end{pmatrix}$   $\begin{pmatrix} 16 \\ 15 \end{pmatrix}$ A2  $X$  A1  $X$  A0  $\sqrt{ }$  Note 1  $1/$ Note 2 A. Any amount of time may pass between bits, as long as SCS stays active high. This allows 8-bit writes to be used.

B. Any additional clock edges encountered after the  $24<sup>th</sup>$  edge are ignored.

### **Figure 24. SDF Timing Diagram 2**

36 *[Submit Documentation Feedback](http://www.go-dsp.com/forms/techdoc/doc_feedback.htm?litnum=SLVSCF7B&partnum=DRV8308)* Copyright © 2014–2017, Texas Instruments Incorporated

#### **Programming (continued)**

### **7.5.3 Programming the OTP Configuration Memory**

<span id="page-35-1"></span>To permanently program the non-volatile OTP memory, first write all the data into the registers as described previously, and then follow this sequence:

![](_page_35_Picture_113.jpeg)

#### **Table 6. Programming the OTP Configuration Memory**

The internal OTP memory can only be programmed once. After programming, the registers can still be overwritten by accesses through the SPI port, or by using an external EEPROM.

#### <span id="page-35-0"></span>**7.6 Register Map**

#### **7.6.1 Control Registers**

The DRV8308 device uses internal registers to set operation parameters, including the characteristics of the speed control loop, commutation settings, gate drive current, and so forth. The registers are programmed through a serial SPI communications interface. In addition, the registers can be permanently programmed into non-volatile OTP memory, or loaded from an external serial EEPROM device.

[Table 7](#page-36-0) is the register map for the device.

**[www.ti.com](http://www.ti.com)** SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017

### **Table 7. Control Register Map**

<span id="page-36-0"></span>![](_page_36_Picture_76.jpeg)

![](_page_37_Picture_0.jpeg)

**[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)** SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

At power-up, when VM rises above the VM reset threshold, or whenever RESET is toggled, the register contents are loaded from the OTP memory or EEPROM (depending on SMODE). For details on external EEPROM connections, see *[External EEPROM Mode](#page-33-2)*. If the OTP has not been programmed and the DRV8308 device is powered-up with SMODE low, the default register values are all 0, except for the FAULT register, which defaults to 0x18. FAULT bits can be cleared by writing 0.

At any time, the register contents may be written or overwritten through the SPI interface.

For detailed descriptions for each register, refer to the prior sections.

<span id="page-37-0"></span>![](_page_37_Picture_303.jpeg)

#### **Table 8. Register Descriptions**

(1)  $R = Read Only$ ; RW = Read or Write. Fault registers can only be written 0.

![](_page_38_Picture_0.jpeg)

#### **Table 8. Register Descriptions (continued)**

<span id="page-38-0"></span>![](_page_38_Picture_345.jpeg)

Product Folder Links: *[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)*

**[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)** SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

#### **Table 8. Register Descriptions (continued)**

<span id="page-39-0"></span>![](_page_39_Picture_355.jpeg)

![](_page_40_Picture_0.jpeg)

#### <span id="page-40-0"></span>**8 Application and Implementation**

#### **NOTE**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### <span id="page-40-1"></span>**8.1 Application Information**

#### **8.1.1 Internal Speed Control Loop Constraints**

The DRV8308 device is a versatile speed controller and driver for small, 3-phase brushless motors. However, there are some limitations to its application.

The built-in speed control loop is designed to work optimally with motor electrical speeds from about 50 Hz up to 6.7 kHz. For an 8-pole motor, this translates into about 500 RPM up to more than 100000 RPM. For motors with higher pole counts, these speeds scale down; for lower pole counts, they scale up.

Operation is possible at slower or faster speeds, but speed control becomes less effective, especially if using the Hall sensors for speed feedback (as opposed to the FG input).

Typically, the speed loop is optimized (by setting the filter coefficients and gains) at one desired motor speed. Operation is possible with one set of parameters over a limited speed range (for example, 1000 RPM to 2000 RPM), However, operation over a very wide speed range requires different parameters. The use of the auto gain and auto advance features can extend the dynamic range up to 4×.

When using the SPI interface to program the registers, the parameters can be updated at any time, even while the motor is running. In this manner, a wider range of speeds can be accommodated by the speed loop.

When not using the internal speed loop (when controlling the motor using PWM input or register speed control), the limits imposed by the speed loop do not apply. An external speed control implementation (using a microcontroller, FPGA, or other logic) can essentially control the motor current directly.

However, if using sine commutation, there are limits to the minimum and maximum speed, which are dictated by the timers that are used to generate the commutation sequence. The commutation timer is a 25-bit timer clocked at 50 MHz; therefore, the longest time it can capture is 655 ms. This limits the slowest speed to about 1.5 Hz (or 23 RPM for an 8-pole motor). At the other extreme, there are 960 steps in each sine commutation cycle. To ensure that there is enough time for the steps, the maximum speed is that which generates 960 counts at 50 MHz, or 52 kHz. This corresponds to a maximum speed of 800000 RPM for an 8-pole motor.

When not using the internal speed loop and using 120° commutation (using all three Hall sensors), there are no speed limitations. Commutation is performed with combinational logic.

#### **8.1.2 Hall Sensor Configurations and Connections**

The Hall sensor inputs on the DRV8308 device are capable of interfacing with a variety of Hall sensors. Typically, a Hall element is used, which outputs a differential signal on the order of 100 mV. To use this type of sensor, the VREG5 regulator can be used to power the Hall sensor. Connections are as shown in [Figure 25](#page-41-0):

### **Application Information (continued)**

![](_page_41_Figure_4.jpeg)

**Figure 25. Hall Sensor Connections**

<span id="page-41-0"></span>Since the amplitude of the Hall sensor output signal is very low, often capacitors are placed across the Hall inputs to help reject noise coupled from the motor PWM. Typically capacitors from 1 to 100 nF are used.

Some motors use digital Hall sensors with open-drain outputs. These sensors can also be used with the DRV8308 device, with the addition of a few resistors:

![](_page_41_Figure_8.jpeg)

**Figure 26. Hall Resistors**

The negative (xHN) inputs are biased to 2.5 V by a pair of resistors between VREG and ground. For opencollector Hall sensors, an additional pullup resistor to VREG is needed on the positive (xHP) input. Again, the VREG output can usually be used to supply power to the Hall sensors.

#### **8.1.3 FG Amplifier Configurations and Connections**

To improve speed control by providing a higher bandwidth speed feedback, often a magnetic pickup coil, commonly referred to as an FG generator, is used. This is typically implemented as a serpentine PCB trace on the motor PCB. This generates a low-level sine wave signal whose amplitude and frequency is proportional to the speed of the motor.

![](_page_42_Picture_0.jpeg)

#### **Application Information (continued)**

Since the FG trace is in close proximity to the motor coils, it is very susceptible to noise coupling from the PWM of the motor. Noise coupling into the FG circuit causes poor speed regulation, especially at low motor speeds. Startup is a particularly difficult situation, as the motor current is at a maximum, and the FG signal amplitude is low (in fact, 0 at the moment of startup). If noise couples into FG during startup, the speed loop interprets the noise as fast motor rotation, and lowers the PWM duty cycle. The result is slow startup of the motor. If this problem is suspected, looking at the FGOUT signal with an oscilloscope during startup should reveal it.

To address this, in addition to the resistors that set the gain of the FG amplifier (R1 and R2 in [Figure 27\)](#page-42-0), usually passive filter components are needed on the FG amplifier circuit.

![](_page_42_Figure_6.jpeg)

**Figure 27. FG Amplifier Circuit**

<span id="page-42-0"></span>Ideally, the user desires a large amount of rejection of the PWM frequency. However, the user needs to pass the frequency that corresponds to their fastest motor speed. As an example, a motor may put out 36 FG pulses per revolution. At 5000 RPM, this is a 3-kHz signal. If you operate the PWM at 25 kHz, you can set a single pole at 3 kHz and have significant rejection of the PWM frequency, and the higher harmonics of the PWM (which are typically more easily coupled) are rejected even more.

Because the amplitude of the FG signal also increases with higher motor speed, it is possible to set this pole at a much lower frequency than the maximum speed dictates. The optimal values need to be determined by testing on the actual motor.

This pole is set by C3 in [Figure 27.](#page-42-0)

In addition to rejection of high frequency, the FG winding should be AC-coupled to the amplifier to prevent any issues with DC offsets. This capacitor (C1) must be large enough to allow the motor to start-up reliably, since the FG frequency and amplitude are very low at startup. Typically capacitors on the order of 100 nF to 1  $\mu$ F are used here. The voltage is low, so a 6.3-V ceramic capacitor can be used.

Occasionally an additional small capacitor is used across the FG trace. This capacitor (C2 above) may not be needed, but it can help reject very high-frequency harmonics of the PWM (glitches). Capacitors between 330 and 2200 pF are typically used.

![](_page_43_Picture_0.jpeg)

### **8.2 Typical Application**

<span id="page-43-0"></span>![](_page_43_Figure_4.jpeg)

![](_page_43_Figure_5.jpeg)

#### **Typical Application (continued)**

#### **8.2.1 Design Requirements**

This section describes design considerations.

![](_page_44_Picture_252.jpeg)

#### **8.2.2 Detailed Design Procedure**

#### *8.2.2.1 Motor voltage*

BLDC motors are typically rated for a certain voltage. Higher voltages generally have the advantage of causing current to change faster through the inductive windings, which allows for higher RPMs. And for a given required power delivery (torque \* speed), higher voltage allows for lower current.

#### *8.2.2.2 Motor Current (Peak and RMS)*

It is important to understand and control motor current. This affects power FET device selection, the amount of required bulk capacitance, and the sizing of the sense resistor for the DRV8308 current-limiter feature.

With BLDC motors, increasing the load torque increases current. For a fixed load, the current during motor spinup is the highest. It is generally a good idea to limit spin-up current by sizing sense resistors appropriately, because if it's not limited, a motor can consume many amperes during startup and cause VM to droop unless a large amount of bulk capacitance is used. Limiting current reduces the bulk capacitance required.

The DRV8308 V<sub>LIMITER</sub> trips at 0.25V. If the sense resistance is 0.025Ω for example, 10A will be required to raise the ISEN voltage above 0.25V. When this happens, the DRV8308 drives the external FETs with a shorter duty cycle to limit current below 10A.

When selecting the power FET device, key parameters to consider are:

- It must be N-channel type, and 6 are needed.
- The max drain current  $(I_D)$ ; pulsed and continuous.
- Max  $V_{DS}$  must be greater than  $V_M$ .
- Max  $V_{GS}$  must be at least 12V (the DRV8308 drives approximately 10V).
- $R_{DS(ON)}$  lower values decrease device temperature.

#### *8.2.2.3 Speed Command Method*

The DRV8308 can drive BLDCs using an open-loop 0% to 100% command, or using closed-loop speed control. When using closed-loop, the correct reference clock frequency (on CLKIN) must be calculated.

If DRV8308 register FGSEL is set to 00b to use Hall U to sense motor speed,

$$
f_{CLKIN} = \text{RPM} / 60 \cdot (N_{POLES} / 2)
$$

 $N_{\text{POI ES}}$  is the number of permanent magnet poles.

If DRV8308 register FGSEL is set to 10b to use FG to sense motor speed,

 $f_{\text{CI KIN}} = \text{RPM} / 60 * N_{\text{FG}}$ 

 $N_{FG}$  is the number of FG cycles per motor revolution.

(5)

(6)

![](_page_45_Picture_0.jpeg)

SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

#### *8.2.2.4 Required Flutter (Speed Jitter)*

Flutter is a measure of motor speed consistency. The best possible flutter largely depends on motor characteristics, loading, and tuning of the DRV8308 registers. BLDC motors with high detent torque and discrete positions will have higher flutter. The *DRV8308EVM User's Guide* [SLVUA41](http://www.ti.com/lit/pdf/slvua41) describes the important registers and a tuning process.

#### *8.2.2.5 Configuration Method*

The DRV8308 must have its registers set in order to function. There are 3 methods:

- 1. Pre-program an external EEPROM, and set pin SMODE High.
- 2. Set pin SMODE Low, and write register data over SPI while the DRV8308 is powered.
- 3. Set pin SMODE Low, write register data over SPI while the DRV8308 is powered, and burn it to the internal EPROM (OTP). Then on future power ups, the DRV8308 will load the custom configuration data.

If the DRV8308 will be used in an open-loop PWM mode, the following register settings provide good baseline settings:

![](_page_45_Picture_186.jpeg)

#### *8.2.2.6 Hall Element Current*

Hall elements output a differential voltage that is proportional to the amount of bias current. An absolute max current is specified, as well as the element resistance over temperature.

The DRV8308 regulated outputs VREG or VSW can be used to supply Hall element current, along with a series resistor to limit element current. Its sizing depends on the element equivalent resistance (they can be arranged in parallel or serial), and the VM voltage if VSW is used.

#### *8.2.2.7 Power FET Switching Time*

The switching time on the external FETs is the  $V_{GS}$  rise time, and it can be easily controlled with DRV8308 register IDRIVE. The 10mA setting causes a switching time that is 5 times the 50mA setting. Larger FETs that have higher current capabilities have a larger gate charge ( $\mathsf{Q}_{\mathsf{g}}$ ), and require higher IDRIVE settings for reasonable switching times.

However, fast switching times can cause extra voltage noise on VM and GND. This can be especially due to a relatively slow reverse-recovery time of the low-side body diode, where it conducts reverse-bias momentarily, being similar to shoot-through. To minimize noise, lower IDRIVE settings are often beneficial, and the 10mA setting has worked well with many types of FETs operating below 5A.

![](_page_46_Picture_0.jpeg)

#### **8.2.3 Application Curves**

![](_page_46_Figure_4.jpeg)

# Texas<br>Instruments

#### **[DRV8308](http://www.ti.com/product/drv8308?qgpn=drv8308)**

SLVSCF7B –FEBRUARY 2014–REVISED NOVEMBER 2017 **[www.ti.com](http://www.ti.com)**

![](_page_47_Figure_3.jpeg)

![](_page_48_Picture_0.jpeg)

#### <span id="page-48-0"></span>**8.3 Do's and Don'ts**

#### **8.3.1 RESET and ENABLE Considerations**

Since the ENABLE function doubles as a sleep (low-power shutdown) function, there are some important considerations when asserting and deasserting ENABLE and RESET.

While the motor driver is enabled, the deassertion of ENABLE initiates a stop-and-power-down sequence. This sequence starts by disabling the motor (either braking or coasting depending on the BRKMOD bit), and waiting for rotation to stop. After rotation is stopped for 1 s (as determined by the absence of transitions on FGOUT), the internal circuitry is powered-down, the V5 regulator and power switch are disabled, and internal clocks are stopped.

In this low-power sleep state, the serial interface may still be used to read or write registers. All other logic is disabled.

After this stop-and-power-down sequence has been initiated (by deasserting the ENABLE pin for at least 1.2 µs, or by changing the state of the ENPOL bit), the sequence continues to completion, regardless of the state of ENABLE. If ENABLE is immediately returned to the active state, the motor slows and stops for 1 s, at which point it starts again.

If RESET is asserted during power-down (at any time after the deassertion of ENABLE is recognized), it is acted upon when ENABLE is again asserted, and the part powers-up.

If RESET is asserted when ENABLE is active, the motor is stopped similar to the sequence when ENABLE is deasserted. After it is stopped for 1 s, all internal registers are reloaded with the value contained in OTP memory, faults are cleared, and internal states (that is, the speed loop datapath) are initialized. The motor remains disabled until RESET is deasserted.

RESET and ENABLE may be connected together (if the ENPOL bit in OTP memory is programmed so that ENABLE is active low). When both signals are low, the motor is enabled; when both signals are high, the motor is disabled. As soon as the signals are returned to high, all registers are reloaded from OTP memory, faults are cleared, and the motor starts.

![](_page_49_Picture_1.jpeg)

#### <span id="page-49-0"></span>**9 Power Supply Recommendations**

The DRV8308 device is designed to operate from an input voltage supply range between 8.5 and 32 V. This supply should be well regulated. A minimum bulk capacitance of  $47-\mu$ F should be used to stabilize the motor voltage.

### <span id="page-49-1"></span>**10 Layout**

#### <span id="page-49-2"></span>**10.1 Layout Guidelines**

For VM, place a 0.1-µF bypass capacitor close to the device. Take care to minimize the loop formed by the bypass capacitor connection from VM to GND. Refer to the DRV8308EVM evaluation board for good layout practices.

#### <span id="page-49-3"></span>**10.2 Layout Example**

![](_page_49_Figure_9.jpeg)

**Figure 39. Layout Example**

![](_page_50_Picture_0.jpeg)

### <span id="page-50-0"></span>**11 Device and Documentation Support**

#### <span id="page-50-1"></span>**11.1 Documentation Support**

#### **11.1.1 Related Documentation**

For related documentation see the following:

- Texas Instruments, *[DRV8308 User's Guide](http://www.ti.com/lit/pdf/slvua41)*
- Texas Instruments, *[Hardware Design Considerations for an Efficient Vacuum Cleaner Using a BLDC Motor](http://www.ti.com/lit/pdf/SLVA654)* [application report](http://www.ti.com/lit/pdf/SLVA654)
- Texas Instruments, *[Understanding IDRIVE and TDRIVE in TI Motor Gate Drivers](http://www.ti.com/lit/pdf/SLVA714)* application report

#### <span id="page-50-2"></span>**11.2 Receiving Notification of Documentation Updates**

<span id="page-50-8"></span>To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### <span id="page-50-3"></span>**11.3 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of](http://www.ti.com/corp/docs/legal/termsofuse.shtml) [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

**[TI E2E™ Online Community](http://e2e.ti.com)** *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**[Design Support](http://support.ti.com/)** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### <span id="page-50-4"></span>**11.4 Trademarks**

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

#### <span id="page-50-5"></span>**11.5 Electrostatic Discharge Caution**

![](_page_50_Picture_19.jpeg)

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### <span id="page-50-6"></span>**11.6 Glossary**

#### [SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

### <span id="page-50-7"></span>**12 Mechanical, Packaging, and Orderable Information**

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

![](_page_51_Picture_0.jpeg)

www.ti.com 10-Dec-2020

### **PACKAGING INFORMATION**

![](_page_51_Picture_228.jpeg)

**(1)** The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

**(3)** MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**(4)** There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

**(5)** Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

**(6)** Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

![](_page_52_Picture_0.jpeg)

## **PACKAGE OPTION ADDENDUM**

## **PACKAGE MATERIALS INFORMATION**

Texas<br>Instruments

### **TAPE AND REEL INFORMATION**

![](_page_53_Figure_4.jpeg)

![](_page_53_Figure_5.jpeg)

#### **QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

![](_page_53_Figure_7.jpeg)

![](_page_53_Picture_198.jpeg)

TEXAS<br>INSTRUMENTS

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Aug-2017

![](_page_54_Figure_4.jpeg)

\*All dimensions are nominal

![](_page_54_Picture_74.jpeg)

## **GENERIC PACKAGE VIEW**

## **RHA 40 VQFN - 1 mm max height**

**6 x 6, 0.5 mm pitch** PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

![](_page_55_Picture_6.jpeg)

![](_page_55_Picture_7.jpeg)

![](_page_56_Picture_1.jpeg)

## **PACKAGE OUTLINE**

## **RHA0040E VQFN - 1 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD

![](_page_56_Figure_5.jpeg)

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

![](_page_56_Picture_10.jpeg)

## **EXAMPLE BOARD LAYOUT**

## **RHA0040E VQFN - 1 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD

![](_page_57_Figure_4.jpeg)

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

![](_page_57_Picture_8.jpeg)

## **EXAMPLE STENCIL DESIGN**

## **RHA0040E VQFN - 1 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD

![](_page_58_Figure_4.jpeg)

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

![](_page_58_Picture_7.jpeg)

### **IMPORTANT NOTICE AND DISCLAIMER**

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale [\(https:www.ti.com/legal/termsofsale.html\)](https://www.ti.com/legal/termsofsale.html) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

> Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021, Texas Instruments Incorporated